

Contents

Acknowledgements	1
Abstract	3
1 Introduction	5
2 Phoxonic crystal structures	13
2.1 Physical background	13
2.1.1 Controlling the properties of materials	13
2.1.2 Similarities between electromagnetic, elastic, and elec- tron waves	14
2.1.3 Electromagnetic waves and photonic crystals	15
2.1.4 Elastic waves and phononic Crystals	19
2.2 Phoxonic crystals	22
2.2.1 1D phoxonic crystal structures	23
2.2.2 2D Phoxonic crystal structurs	37
3 Design of optical cavities	47
3.1 Introduction	47
3.2 Odd cavities	51
3.3 Even cavities	57
3.4 Cross cavity	59
3.5 Linear cavities	70
4 Slow-wave phenomena in phoxonic crystal structures	77
4.1 Slow-wave concept	77
4.2 State-of-the-art in slow waves in periodic media	79
4.3 Coupled resonant acoustic waveguide (CRAW)	84
4.3.1 Numerical CRAW dispersion	85
4.3.2 CRAW dispersion relation	88

4.4	Slow-waveguide in a honeycomb phoXonic crystal structure	94
4.4.1	Honeycomb phoxonic crystal slab	95
4.4.2	Waveguide in lattice phoxonic crystals	96
4.4.3	CRAW model application	103
4.4.4	Group velocity in phoxonic waveguide	104
4.4.5	Highly confined phononic guiding modes	106
4.5	Effect of loss on the dispersion relation of photonic and phononic crystals	108
4.5.1	Perturbation of dispersion relations by material losses	109
4.5.2	Special dispersion relation models.Frozen mode regime in artificial materials.	114
4.5.3	Bandgap model.	121
5	Optical gain in silicon phoxonic cavities	131
5.1	Physical Background	131
5.1.1	Photons	131
5.1.2	Phonons	132
5.1.3	Spontaneous emission, stimulated emission and absorption. Einstein coefficients	135
5.1.4	Purcell factor	138
5.2	State of the art of silicon as emitter	140
5.2.1	Different approaches to achieve a silicon laser	144
5.3	Theoretical study about the gain in indirect bandgap semiconductor optical cavities	148
5.3.1	Increase of the optical gain with Purcell factor	150
5.3.2	Variation of the optical gain, photon density, phonon density, carrier density, oscillation laser threshold and threshold pumping	153
5.3.3	Numerical results	156
5.3.4	Free-carrier absorption and optical gain	159
5.4	Einstein's coefficients for indirect bandgap semiconductors .	161
5.4.1	Einstein's relations for indirect bandgap semiconductor	163
5.5	Optical gain in indirect bandgap semiconductor acousto-optical cavities with simultaneous photon and phonon confinement	170
5.5.1	Acoustic Purcell Factor (APF) and compound IBS cavity Purcell factor	171
5.5.2	Rate equations	175
5.5.3	Increase of the optical gain with Purcell factor	175

5.5.4	Variation of photon density, phonon density, carrier density, oscillation laser threshold and threshold pumping	178
5.5.5	Numerical results	182
5.5.6	Optical gain	183
5.5.7	Collective spontaneous emission. Dicke superradiance structure	186
6	Cavity quantum electrodynamics in optomechanical cavities	195
6.1	Physical background	195
6.1.1	Field quantization	195
6.1.2	Quantum Electrodynamic Cavity. Jaynes-Cummings model	200
6.2	State of art	203
6.3	Jaynes-Cumming model of an indirect gap semiconductor cavity	205
6.3.1	Hamiltonian of non-linear JCM applied to two-level pseudo-atom model	211
6.3.2	Eigenstate and eigenvalue of the Hamiltonian system	212
6.3.3	Rabi oscillations	213
6.3.4	Population inversion: collapse and revival behavior .	215
6.3.5	Theoretical expresion of Rabi frequency oscillation for indirect bandgap semiconductor	220
6.4	Theoretical study of two-level systems inside on optomechanical cavity where mechanical oscillations are induced	223
6.4.1	Evolution operator, population inversion, entropy and purity factor	231
6.4.2	Numerical results	233
7	Conclusions and Prospects	253
Appendix A		255
Author papers		259
Author conferences		261